

**B. E. METALLURGICAL AND MATERIAL ENGINEERING EXAMINATION, 2019**

( 4th Year, 2nd Semester )

**ADVANCED CHARACTERIZATION TECHNIQUES**

Time : Three hours

Full Marks : 100

Use a separate Answer-Script for each Part

**PART - I****(70 Marks)****(Answer question 1 and any three from the rest)**

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|--|--------|
| 1. Discuss the interaction of incident electrons as they transmit through thin solids.   | 10     |
| 2. (a) Assuming the sinusoidal form of wave find the expression for scattered wave from a point scatterer.   | 10     |
| (b) Find the expression for the resultant of amplitude of scattering from a pair of point scatterers.  | 10     |
| 3. (a) Using quantum mechanical concept find the ratio of amplitude of scattered X-ray by an electron to that of a point electron situated at the centre of the atom.  | 15     |
| (b) Find an expression of atomic scattering factor.  | 5      |
| 4 (a) Find an expression for the intensity of electron diffraction using the concept of kinematical theory for thin crystals. Plot the variation of intensity as a function of inverse of thickness of the crystal | 12+2   |
| (b) Find an expression for structure factor  | 6      |
| 5 (a) Define reciprocal lattice. Discuss the graphical representation of diffraction condition. Show that the Bragg diffraction equation can be derived from Laue condition of diffraction.                        | 3+3+10 |
| (b) Discuss the mechanism of image contrast in TEM   | 4      |
| 6 (a) Discuss the principle of AAS and UV-VIS spectroscopy.  | 5+5    |
| (b) Discuss the mechanism of interaction of IR active molecules with electromagnetic radiation.  | 5      |
| (c) Discuss briefly the principle of microwave spectroscopy.   | 5      |

**B.E. METALLURGICAL AND MATERIAL ENGINEERING  
FOURTH YEAR SECOND SEMESTER EXAM – 2019**

**Subject: Advanced Characterisation Techniques**

**Part - II  
(30 Marks)**

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**(Answer Question No. 1 and any one from the rest)**

**1. Answer any six from the following:**

- (a) Why the resolution in scanning electron microscope is higher than optical microscope?
- (b) How the magnification of in scanning electron microscope is decided?
- (c) What is the advantage of AFM over electron microscope?
- (d) Why does scanning electron microscopy require high vacuum of the specimen chamber?
- (e) Can we directly use non-conducting specimen for scanning electron microscopy? If not, what do we need to carry out to study non-conducting specimen in scanning electron microscope?
- (f) What is the need of high voltage in scanning electron microscope?
- (g) What is the purpose of using filter in optical microscopy?
- (h) What is the role of spot size in scanning electron microscopy? 6 x 2.5 = 15

- 2. (a) Briefly discuss the underlying principle for non-contact mode of atomic force microscopy. 5
- (b) Briefly discuss the principle for microanalysis by EDS. Highlight the difference between EDS and WDS. 5 + 2 = 7
- (c) What additional information are obtained in case of BSE imaging as compared to SE imaging in scanning electron Microscopy and why? 3

- 3. (a) Discuss the principle for differential thermal analysis (DTA) for phase transformation of materials? Why powdered sample is used for DTA instead of bulk specimen? 5 + 2 = 7

- (b) What is the importance of dilatometry in studying phase transformation of steel? Design an experiment to study the austenite transformation kinetics in case of a plain carbon eutectoid steel by dilatometry. 2 + 6 = 8